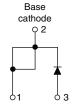


# Ultrafast Rectifier, 8 A FRED Pt®







#### **FEATURES**

- · Ultrafast and soft recovery time
- · Optimized forward voltage drop
- Polyimide passivation
- 175 °C maximum operating junction temperature
- · Rugged design
- · Good thermal performance
- Meets JESD 201 class 2 whisker test







### **RoHS** HALOGEN FREE

PRODUCT SUMMARY	DE,	
I <sub>F(AV)</sub>	8 A	Ultra
$V_{R}$	1200 V	volta Polv
		. 0.5

V<sub>F</sub> at I<sub>F</sub> at 125 °C 1.95 V 42 ns t<sub>rr</sub> typ. 175 °C T<sub>J</sub> max. TO-220AC Package Diode variation Single die

### **DESCRIPTION / APPLICATIONS**

afast recovery rectifiers designed with optimized forward age drop, ultrafast recovery time, and soft recovery. yimide passivated with a planar structure and platinum doped life time control guarantee ruggedness, reliability, and offer a solid value for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery chargers, inverters for solar inverters or as freewheeling diodes in motor drives.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	$V_{RRM}$		1200	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 140 °C, D = 0.50	8				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 10 ms, sine wave	80	А			
Repetitive peak forward current	I <sub>FRM</sub>		16				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 200 μΑ	1200	-	-		
Forward voltage	V	I <sub>F</sub> = 8 A -		2.05	2.55	V	
	V <sub>F</sub>	I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	1.95	2.37		
Deverage leakage assurent		V <sub>R</sub> = V <sub>R</sub> rated	-	-	55		
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	100	μA 100	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	8	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 1.0 \text{ A}$	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{A}, V_R = 30 \text{ V}$		42	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 100 A/μs V <sub>R</sub> = 390 V	-	144	-	ns	
		T <sub>J</sub> = 125 °C		-	204	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	5	-	Α	
		T <sub>J</sub> = 125 °C		-	7.2	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	370	-	200	
		T <sub>J</sub> = 125 °C		-	745	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	1.25	1.5			
Thermal resistance, junction to case R <sub>thJA</sub> Typical socket mount		Typical socket mount	-	54	60	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.18	0.4			
Weight			-	0.2	-	g		
weight			-	0.07	-	oz.		
Mounting torque			6.0	_	12	kgf · cm		
Mounting torque			(5.0)		(10)	(lbf·in)		
Marking device		Case style TO-220AC	8ETU12					

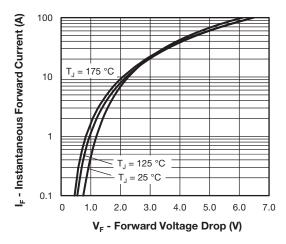


Fig. 1 - Typical Forward Voltage Drop Characteristics

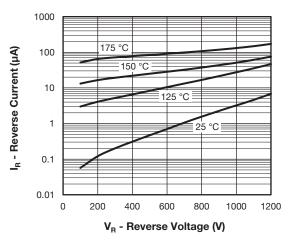


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



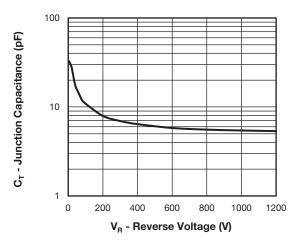


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

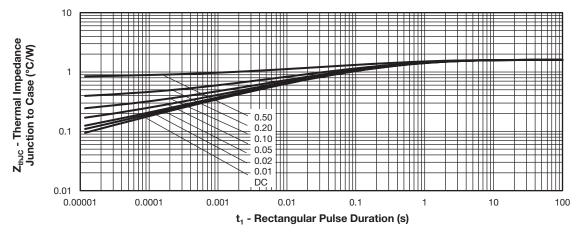


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

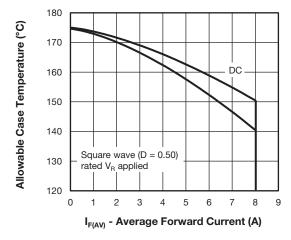


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

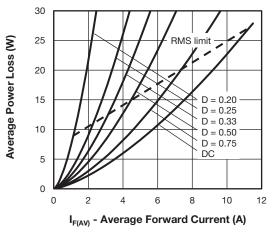


Fig. 6 - Forward Power Loss Characteristics

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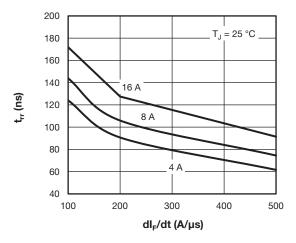


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

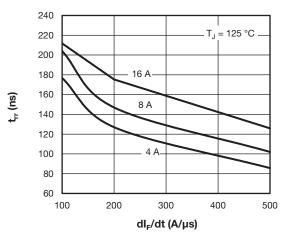


Fig. 8 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

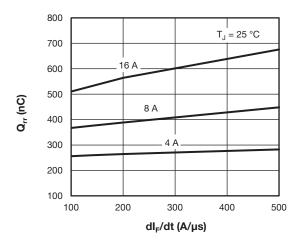


Fig. 9 - Typical Stored Charge vs. dl<sub>F</sub>/dt

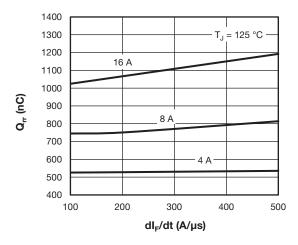


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

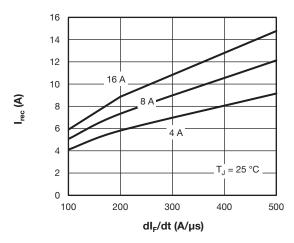


Fig. 11 - Typical Reverse Current vs. dl<sub>F</sub>/dt

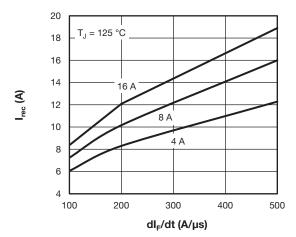
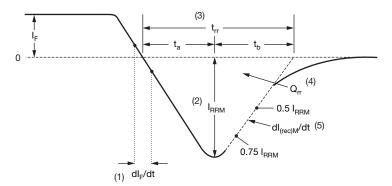


Fig. 12 - Typical Reverse Current vs. dl<sub>F</sub>/dt



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RBM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$

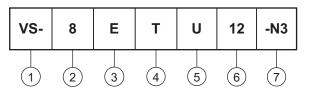
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 13 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

**Device code** 



- Vishay Semiconductors product
- **2** Current rating (8 = 8 A)
- 3 E = single diode
- 4 Package:

T = TO-220

- 5 U = ultrafast recovery
- 6 Voltage rating (12 = 1200 V)
- 7 Environmental digit:
  - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

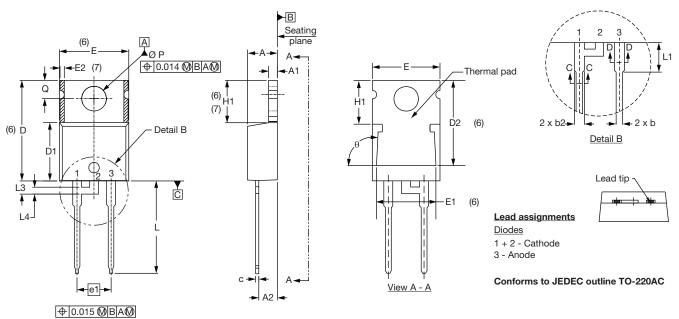
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8ETU12-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95221				
Part marking information	www.vishay.com/doc?95068				



### **TO-220AC**

### **DIMENSIONS** in millimeters and inches



SYMBOL		IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS INCHES		NOTES		
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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